

SCBS261M-JULY 1993-REVISED DECEMBER 2006

FEATURES	SN54LVTH162373 WD PACKAGE
 Members of the Texas Instruments Widebus™ Family 	SN74LVTH162373 DGG OR DL PACKAGE (TOP VIEW)
 Output Ports Have Equivalent 22-Ω Series Resistors, So No External Resistors Are Required 	10E [1 48] 1LE 1Q1 [2 47] 1D1
 Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC}) 	1Q2 [3 46] 1D2 GND [4 45] GND 1Q3 [5 44] 1D3
 Support Unregulated Battery Operation Down to 2.7 V 	$1Q4 \begin{bmatrix} 6 & 43 \end{bmatrix} 1D4 \\ V_{cc} \begin{bmatrix} 7 & 42 \end{bmatrix} V_{cc}$
 Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, T_A = 25°C 	1Q5 [8 41] 1D5 1Q6 [9 40] 1D6
 I_{off} and Power-Up 3-State Support Hot Insertion 	GND [10 39] GND 1Q7 [11 38] 1D7
 Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors 	1Q8 [12 37] 1D8 2Q1 [13 36] 2D1
 Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise 	2Q2 [14 35] 2D2 GND [15 34] GND
 Flow-Through Architecture Optimizes PCB Layout 	2Q3 [16 33] 2D3 2Q4 [17 32] 2D4 Voc [18 31] Voc
 Latch-Up Performance Exceeds 500 mA Per JESD 17 	V _{cc} [18 31] V _{cc} 2Q5 [19 30] 2D5 2Q6 [20 29] 2D6
ESD Protection Exceeds JESD 22	GND [21 28] GND
 2000-V Human-Body Model (A114-A) 	2Q7 [] 22 27]] 2D7
 200-V Machine Model (A115-A) 	2Q8 [23 26] 2D8 2OE [24 25] 2LE

DESCRIPTION/ORDERING INFORMATION

The 'LVTH162373 devices are16-bit transparent D-type latches with 3-state outputs designed for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

ORDERING INFORMATION

T _A	PA	CKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
		Tube of 25	SN74LVTH162373DL			
		Tube of 25	74LVTH162373DLG4	LVTH162373		
SSOP – DL Reel of 1000		SN74LVTH162373DLR				
			74LVTH162373DLRG4			
–40°C to 85°C	TSSOP – DGG	Reel of 2000	SN74LVTH162373DGGR	LVTH162373		
	1330F - DGG	Reel 01 2000	74LVTH162373DGGRE4			
	VFBGA – GQL		SN74LVTH162373KR			
	VFBGA – ZQL (Pb-free)	Reel of 1000	74LVTH162373ZQLR	LL2373		
–55°C to 125°C	CFP – WD	Tube	SNJ54LVTH162373WD	SNJ54LVTH162373WD		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The outputs, which are designed to source or sink up to 12 mA, include equivalent $22-\Omega$ series resistors to reduce overshoot and undershoot.

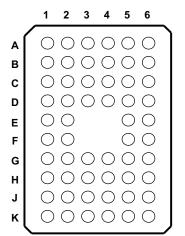
Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

These devices can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

GQL OR ZQL PACKAGE (TOP VIEW)



TERMINAL ASSIGNMENTS⁽¹⁾

	1	2	3	4	5	6
Α	1 0E	NC	NC	NC	NC	1LE
В	1Q2	1Q1	GND	GND	1D1	1D2
С	1Q4	1Q3	V _{CC}	V _{CC}	1D3	1D4
D	1Q6	1Q5	GND	GND	1D5	1D6
Е	1Q8	1Q7			1D7	1D8
F	2Q1	2Q2			2D2	2D1
G	2Q3	2Q4	GND	GND	2D4	2D3
н	2Q5	2Q6	V _{CC}	V _{CC}	2D6	2D5
J	2Q7	2Q8	GND	GND	2D8	2D7
к	2 <mark>0E</mark>	NC	NC	NC	NC	2LE

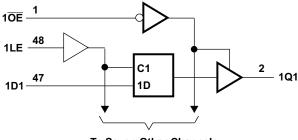
(1) NC - No internal connection

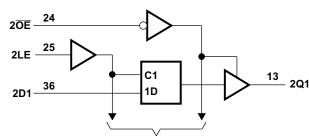
FUNCTION TABLE (each 8-bit section)

	INPUTS	OUTPUT	
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Х	Q ₀
Н	Х	Х	Z

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LOGIC DIAGRAM (POSITIVE LOGIC)





To Seven Other Channels

To Seven Other Channels

Pin numbers shown are for the DGG, DL, and WD packages.

Absolute Maximum Ratings⁽¹⁾

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in th	e high-impedance or power-off state ⁽²⁾	-0.5	7	V
Vo	Voltage range applied to any output in th	e high state ⁽²⁾	-0.5	V _{CC} + 0.5	V
I _O	Current into any output in the low state			30	mA
I _O	Current into any output in the high state	3)		30	mA
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
		DGG package		70	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DL package		63	°C/W
		GQL/ZQL package		42	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) This current flows only when the output is in the high state and $V_0 > V_{CC}$.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

			5	SN54LVTH1	62373	SN74LVTH1	62373	
				MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage range			2.7	3.6	2.7	3.6	V
V _{IH}	High-level input voltage			2		2		V
V _{IL}	Low-level input voltage				0.8		0.8	V
VI	Input voltage				5.5		5.5	V
I _{OH}	High-level output current				-12		-12	mA
I _{OL}	Low-level output current				12		12	mA
$\Delta t / \Delta v$	Input transition rise or fall rate	Outputs enabled			10		10	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate			200		200		μs/V
T _A	Operating free-air temperature			-55	125	-40	85	°C

 All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

		TEST		SN54LVTH16	2373	SN74LV	TH162373	
PA	RAMETER	TESTC	ONDITIONS	MIN TYP ⁽¹⁾	MAX	ΜΙΝ ΤΥ	'P ⁽¹⁾ MAX	UNIT
V _{IK}		V _{CC} = 2.7 V,	I _I = -18 mA		-1.2		-1.2	V
V _{OH}		V _{CC} = 3 V,	I _{OH} = -12 mA	2		2		V
V _{OL}		V _{CC} = 3 V,	l _{OL} = 12 mA		0.8		0.8	V
		V _{CC} = 0 or 3.6 V,	V _I = 5.5 V		10		10	
	Control inputs	V _{CC} = 3.6 V,	$V_{I} = V_{CC}$ or GND		±1		±1	۵
II.	Doto inputo	V 26V	$V_{I} = V_{CC}$		1		1	μA
	Data inputs	V _{CC} = 3.6 V	$V_{I} = 0$		-5		-5	
I _{off}		$V_{CC} = 0,$	V_{I} or V_{O} = 0 to 4.5 V				±100	μΑ
		V 2V	V _I = 0.8 V	75		75		
ha in	Data inputs	$V_{CC} = 3 V$	V ₁ = 2 V	-75		-75		μA
I _{I(hold)}		$V_{CC} = 3.6 V^{(2)},$	$V_{1} = 0 \text{ to } 3.6 \text{ V}$				500 –750	μπ
I _{OZH}	1	V _{CC} = 3.6 V,	$V_0 = 3 V$		5		5	μΑ
I _{OZL}		V _{CC} = 3.6 V,	V _O = 0.5 V		-5		-5	μΑ
I _{OZPU}		$V_{CC} = 0$ to 1.5 V, $V_O = 0$ $\overline{OE} = $ don't care	0.5 V to 3 V,		±100 ⁽³⁾		±100	μΑ
I _{OZPD}		V_{CC} = 1.5 V to 0, V _O = 0 \overline{OE} = don't care	0.5 V to 3 V,		±100 ⁽³⁾		±100	μΑ
		V _{CC} = 3.6 V,	Outputs high		0.19		0.19	
I _{CC}		$I_{0} = 0,$	Outputs low		5		5	mA
		$V_{I} = V_{CC}$ or GND	Outputs disabled		0.19		0.19	
$\Delta I_{CC}^{(4)}$		$V_{CC} = 3 V$ to 3.6 V, One Other inputs at V_{CC} or G	input at V _{CC} – 0.6 V, ND		0.2		0.2	mA
Ci		V _I = 3 V or 0		3			3	pF
Co		V _O = 3 V or 0		9			9	pF

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STRUMENTS www.ti.com

(1) All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

(2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

(3) On products compliant to MIL-PRF-38535, this parameter is not production tested.

(4) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

Timing Requirements

over operating free-air temperature range (unless otherwise noted) (see Figure 1)

		S	N54LVT	H162373		S				
		V _{CC} = 3 ±0.3	V _{CC} = 3.3 V ±0.3 V		2.7 V	V _{CC} = 3.3 V ±0.3 V		V _{CC} = 2.7 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
tw	Pulse duration, LE high	3		3		3		3		ns
t _{su}	Setup time, data before LE \downarrow	1.3		0.6		1		0.6		ns
t _h	Hold time, data after LE \downarrow	1		1.1		1		1.1		ns

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Switching Characteristics

over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

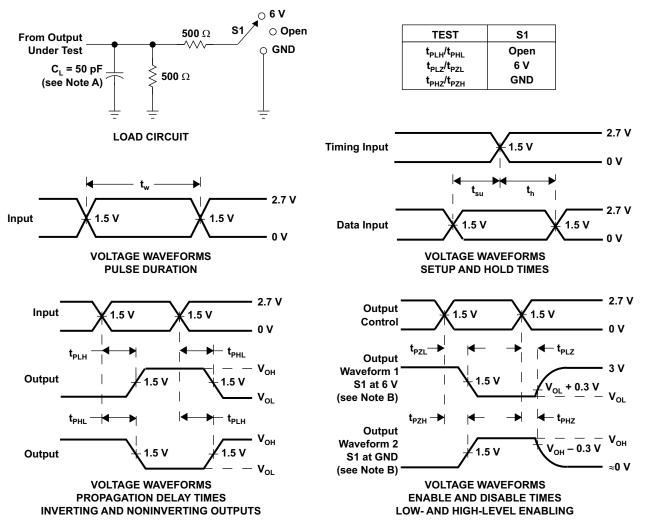
			SI	N54LVT	H16237	3		SN74L	VTH162	2373		
PARAMETER	FROM (INPUT)	TO (OUTPUT)		V _{CC} = 3.3 V ±0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ±0.3 V		V _{CC} = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP ⁽¹⁾	MAX	MIN	MAX	
t _{PLH}	D	0	1.8	5		5.7	1.9	3.1	4.6		5.1	20
t _{PHL}	D	Q	1.8	4.4		4.8	1.9	2.8	4		4.3	ns
t _{PLH}	LE	0	2.1	5.4		6.2	2.2	3.4	5.1		5.8	
t _{PHL}	LE	Q	2.1	4.9		4.7	2.2	3.2	4.6		4.3	ns
t _{PZH}	OE	0	1.7	5.6		7	1.8	3.2	5.4		6.6	
t _{PZL}	UE	Q	1.7	5.3		5.9	1.8	3.2	4.9		5.5	ns
t _{PHZ}	OE	0	2.3	6.3		6.6	2.4	3.8	5.4		5.7	
t _{PLZ}	UE	Q	1	7.4		6.4	2.2	3.5	5.1		5	ns
t _{sk(LH)}									0.5			
t _{sk(HL)}									0.5			ns

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25 ^{\circ}C.

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $t_r \leq 2.5 ns$, $t_f \leq 2.5 ns$.

D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9763801VXA	ACTIVE	CFP	WD	48	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9763801VX A SNV54LVTH16237 3WD	Samples
SN74LVTH162373DGGR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH162373	Samples
SN74LVTH162373DL	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH162373	Samples
SN74LVTH162373DLR	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH162373	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



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14-Feb-2021

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OTHER QUALIFIED VERSIONS OF SN54LVTH162373, SN54LVTH162373-SP, SN74LVTH162373 :

- Catalog: SN74LVTH162373, SN54LVTH162373
- Enhanced Product: SN74LVTH162373-EP, SN74LVTH162373-EP
- Military: SN54LVTH162373
- Space: SN54LVTH162373-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH162373DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74LVTH162373DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1



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PACKAGE MATERIALS INFORMATION

5-Jan-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH162373DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74LVTH162373DLR	SSOP	DL	48	1000	367.0	367.0	55.0



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5-Jan-2022

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74LVTH162373DL	DL	SSOP	48	25	473.7	14.24	5110	7.87

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-153.



DGG0048A

DGG0048A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DGG0048A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate

design recommendations. 8. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



MECHANICAL DATA

MCFP010B - JANUARY 1995 - REVISED NOVEMBER 1997

CERAMIC DUAL FLATPACK

WD (R-GDFP-F**)

48 LEADS SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only
 - E. Falls within MIL STD 1835: GDFP1-F48 and JEDEC MO-146AA
 - GDFP1-F56 and JEDEC MO-146AB



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